

UNISONIC TECHNOLOGIES CO., LTD

UMY1N

Preliminary

DUAL TRANSISTOR

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DESCRIPTION

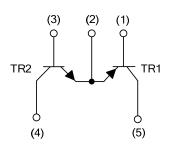
The UTC **UMY1N** is a dual transistor, including a NPN and a PNP which have common emitters. it uses UTC's advanced technology to provide customers with high DC current gain, etc.

FEATURES

* PNP and NPN transistors have common emitters

* High DC current gain

EQUIVALENT CIRCUIT

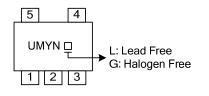


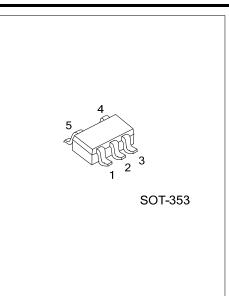
ORDERING INFORMATION

Order	Order Number		Pin Assignment					Dealise	
Lead Free	Halogen Free	Package	1	2	3	4	5	Packing	
UMY1NL-AL5-R	UMY1NG-AL5-R	SOT-353	B1	E1, E2	B2	C2	C1	Tape Reel	

UMY1NL- <u>AL5</u> -R T	(1)Packing Type	(1) R: Tape Reel	
	(2)Package Type	(2) AL5: SOT-353	
	(3)Lead Free	(3) L: Lead Free, G: Halogen Free	

MARKING INFORMATION





■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

DADAMETED	0)(MDO)	RAT			
PARAMETER	SYMBOL -	TR1	TR2	UNIT	
Collector-Base Voltage	V _{CBO}	-60	60	V	
Collector-Emitter Voltage	V _{CEO}	-50	50	V	
Emitter-Base Voltage	V _{EBO}	-6	7	V	
Continuous Collector Current	lc	-150	150	mA	
Collector Power Dissipation	Pc	150		mW	
Junction Temperature	TJ	150		°C	
Storage Temperature	T _{STG}	-55~+150		°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
TR1							
Collector-Base Breakdown Voltage	BV _{CBO}	I _C =-50μΑ, I _E =0	-60			V	
Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C =-1mA, I _B =0	-50			V	
Emitter-Base Breakdown Voltage	BV _{EBO}	I _E =-50μΑ, I _C =0	-6			V	
Collector Cut-Off Current	I _{CBO}	V _{CB} =-60V, I _E =0			-0.1	μA	
Emitter Cut-Off Current	I _{EBO}	V _{EB} =-6V, I _C =0			-0.1	μA	
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I _C =-50mA, I _B =-5mA			-0.5	V	
DC Current Gain	h _{FE}	V _{CE} =-6V, I _C =-1mA	120		560		
Transition Frequency	f⊤	V _{CE} =-12V, I _E =-2mA, f=100MHz		140		MHz	
Output Capacitance	C _{ob}	V _{CB} =-12V, I _E =0, f=1MHz			5	рF	
TR2							
Collector-Base Breakdown Voltage	BV _{CBO}	I _C =50μA, I _E =0	60			V	
Collector-Emitter Breakdown Voltage	BV _{CEO}	$I_{C}=1mA$, $I_{B}=0$	50			V	
Emitter-Base Breakdown Voltage	BV_{EBO}	I _E =50μA, I _C =0	7			V	
Collector Cut-Off Current	I _{CBO}	V_{CB} =60V, I _E =0			0.1	μA	
Emitter Cut-Off Current	I _{EBO}	$V_{EB}=7V, I_{C}=0$			0.1	μA	
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I _C =50mA, I _B =5mA			0.4	V	
DC Current Transfer Ratio h _{FE}		V _{CE} =6V, I _C =1mA	120		560		
Transition Frequency f _T		V _{CE} =12V, I _E =2mA, f=100MHz		180		MHz	
Output Capacitance	Cob	V _{CB} =12V, I _E =0, f=1MHz			3.5	pF	



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